

ISA1399AS1

FOR GENERAL PURPOSE HIGH CURRENT DRIVE APPLICATION
SILICON PNP EPITAXIAL TYPE

DESCRIPTION

ISA1399AS1 is a silicon PNP epitaxial type transistor designed with High collector current, high voltage. Complementary with ISA3581AS1.

FEATURE

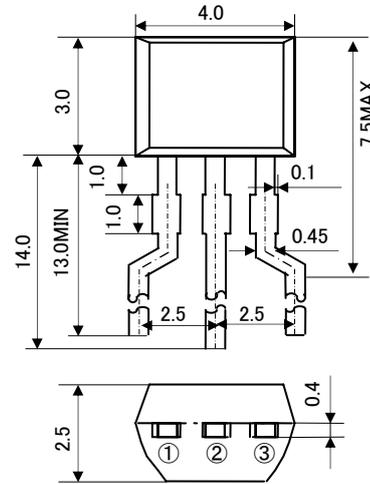
- High collector current. $I_{CM}=600\text{mA}$
- High gain band width product. $fT=150\text{MHz}$ typ
- High V_{CEO} . $V_{CEO}=-50\text{V}$
- Excellent linearity of DC forward current gain.

APPLICATION

For switching, small type motor drive application.

OUTLINE DRAWING

Unit: mm



JEITA:
JEDEC:

TERMINAL CONNECTER

- ①: EMITTER
- ②: COLLECTOR
- ③: BASE

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

Symbol	Parameter	Ratings	Unit
V_{CBO}	Collector to Base voltage	-55	V
V_{EBO}	Emitter to Base voltage	-4	V
V_{CEO}	Collector to Emitter voltage	-50	V
I_C	Collector current	-400	mA
I_{CM}	Peak collector current	-600	mA
P_c	Collector dissipation	600	mW
T_j	Junction temperature	+150	$^\circ\text{C}$
T_{stg}	Storage temperature	-55 ~ +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)

Parameter	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
$V_{(BR)CBO}$	C to B break down voltage	$I_C = -10 \mu\text{A}$, $I_E = 0$	-55	-	-	V
$V_{(BR)EBO}$	E to B break down voltage	$I_E = -10 \mu\text{A}$, $I_C = 0$	-4	-	-	V
$V_{(BR)CEO}$	C to E break down voltage	$I_C = -100 \mu\text{A}$, $R_{BE} = \infty$	-50	-	-	V
I_{CBO}	Collector cut off current	$V_{CB} = -25\text{V}$, $I_E = 0\text{mA}$	-	-	-1	μA
I_{EBO}	Emitter cut off current	$V_{EB} = -2\text{V}$, $I_C = 0\text{mA}$	-	-	-1	μA
$h_{FE}\text{※}$	DC forward current gain	$V_{CE} = -4\text{V}$, $I_C = -100\text{mA}$	90	-	500	-
$V_{CE(sat)}$	C to E Saturation Voltage	$I_C = -200\text{mA}$, $I_B = -10\text{mA}$	-	-0.17	-0.5	V
fT	Gain band width product	$V_{CE} = -6\text{V}$, $I_E = 10\text{mA}$	-	150	-	MHz

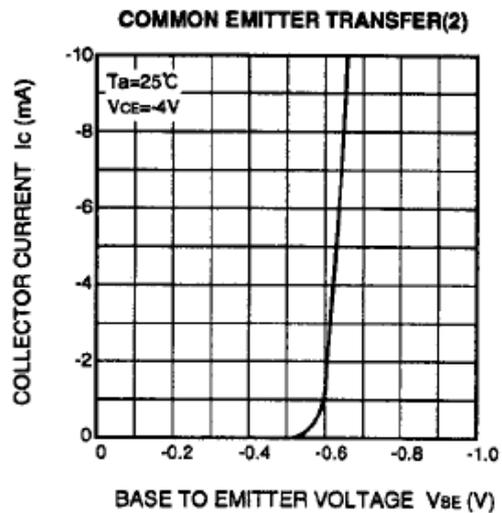
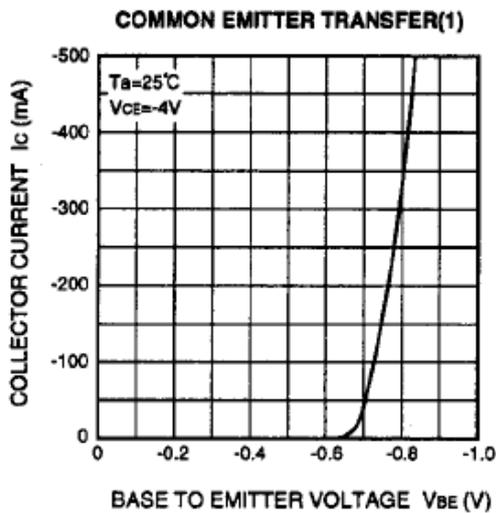
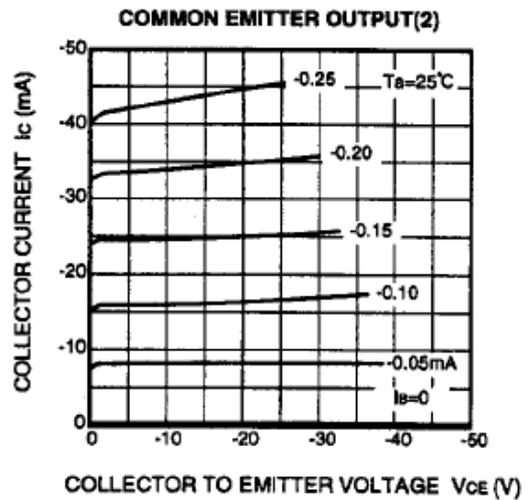
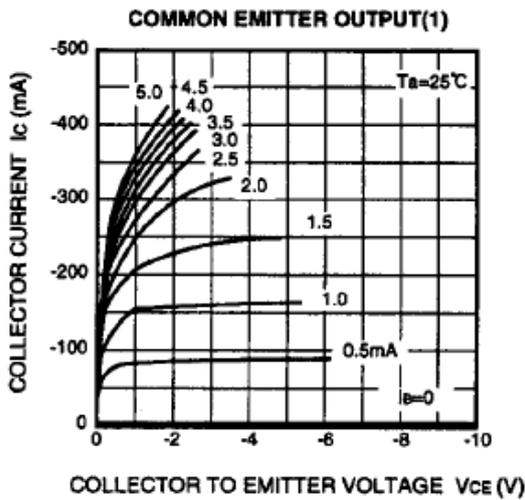
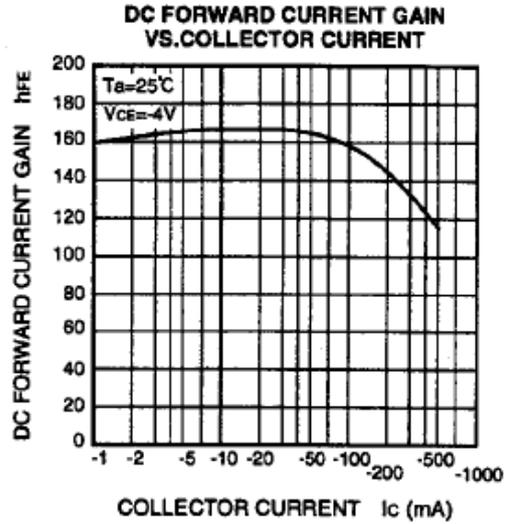
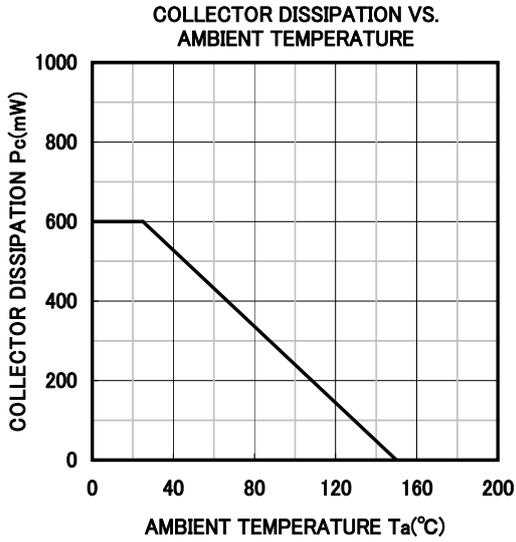
※) It shows h_{FE} classification in right table.

Item	D	E	F
h_{FE} item	90~180	150~300	250~500

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TYPICAL CHARACTERISTICS





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